

### PNP -500mA -40V Digital Transistors (Bias Resistor Built-in Transistors)

Parameter	Value
$V_{CEO}$	-40V
I <sub>C</sub>	-500mA
R	10kΩ

# SMT3 Collector Emitter DTB114TK

SOT-346 (SC-59)

### Features

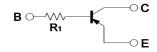
- 1) Built-In Biasing Resistors
- Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see inner circuit).
- 3) The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of completely eliminating parasitic effects.
- 4) Only the on/off conditions need to be set for operation, making the circuit design easy.
- 5) Lead Free/RoHS Compliant.

### Application

Switching circuit, Inverter circuit, Interface circuit, Driver circuit

### •Inner circuit

Outline



### Packaging specifications

Part No.	Package	Package size (mm)	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit (pcs)	Marking
DTB114TK	SMT3	2928	T146	180	8	3,000	F94

### ● Absolute maximum ratings (Ta = 25°C)

Parameter	Symbol	Values	Unit
Collector-base voltage	V <sub>CBO</sub>	-50	V
Collector-emitter voltage	V <sub>CEO</sub>	-40	V
Emitter-base voltage	$V_{EBO}$	<b>-5</b>	V
Collector current	I <sub>C</sub>	-500	mA
Collector Power dissipation	P <sub>d</sub> *2	200	mW
Junction temperature	T <sub>j</sub>	150	°C
Range of storage temperature	T <sub>stg</sub>	−55 to +150	°C

### ●Electrical characteristics(Ta = 25°C)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Collector-base breakdown voltage	BV <sub>CBO</sub>	$I_C = -50 \mu A$	-50	1	-	V
Collector-emitter breakdown voltage	BV <sub>CEO</sub>	I <sub>C</sub> = -1mA	-40	-	-	V
Emitter-base breakdown voltage	$BV_{EBO}$	$I_E = -50 \mu A$	-5	-	1	V
Collector cut-off current	I <sub>CBO</sub>	$V_{CB} = -50V$	1	-	-0.5	μΑ
Emitter cut-off current	I <sub>EBO</sub>	$V_{EB} = -4V$	ı	ı	-0.5	μΑ
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	$I_{\rm C}$ / $I_{\rm B}$ = -10mA / -0.5mA	ı	ı	-0.3	V
DC current gain	h <sub>FE</sub>	$V_{CE} = -5V$ , $I_C = -50mA$	100	250	600	-
Emitter-base resistance	R	-	ı	10	ı	kΩ
Transition frequency	f <sub>T</sub> *1	$V_{CE} = -10V, I_{E} = 50mA,$ f = 100MHz	-	200	-	MHz

<sup>\*1</sup> Characteristics of built-in transistor

<sup>\*2</sup> Each terminal mounted on a reference footprint

### ●Electrical characteristic curves(Ta = 25°C)

Fig.1 Grounded emitter propagation

Characteristics

-10

V<sub>CE</sub>= -5V

-1

-0.1

-0.01

-0.01

-0.001

-0.05

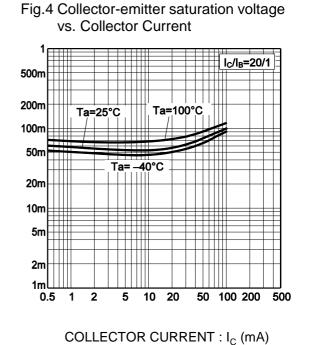
-1

-1.5

BASE TO EMITTER VOLTAGE: V<sub>BE</sub> (V)

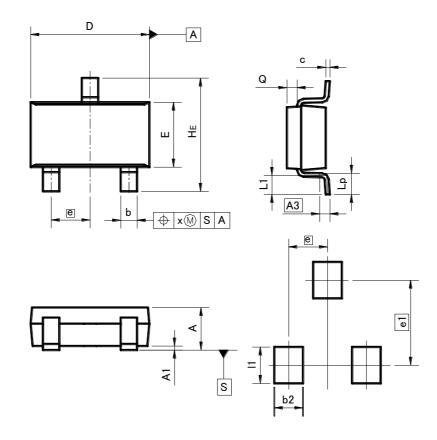
Fig.2 Grounded emitter output characteristics  $I_B = -1.0 \text{mA}$ -200 -0.9mA COLLECTOR CURRENT: I<sub>C</sub> (mA) -0.8mA -150 -0.7mA -0.6mA -0.5mA -100 -0.4mA -0.3mA -50 -0.2mA -0.1mA Ta=25°C 0A 0 -2 -4 0 -6 -8 -10 **COLLECTOR TO EMITTER** VOLTAGE: V<sub>CE</sub> (V)

Fig.3 DC Current gain vs. Collector Current Ta=25°C V<sub>CE</sub>=5V Ta=100°C COLLECTOR SATURATION VOLTAGE: V<sub>CE</sub>(sat) (V) 200 DC CURRENT GAIN: hFE Ta= -40°C 100 50 20 10 0.5 1 10 50 100 200 COLLECTOR CURRENT: I<sub>C</sub> (mA)



### ●Dimensions (Unit:mm)

### SMT3



### **Patterm of terminal position areas**

DIM	MILIMI	ETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	1.00	1.30	_	0.051	
A1	0.00	0.10	0	0.004	
A3	0.25		0.0	01	
b	0.35	0.50	0.014	0.02	
С	0.09	0.25	0.004	0.01	
D	2.80	3.00	0.11	0.118	
E	1.50	1.80	0.059	0.071	
е	0.95		0.0	04	
HE	2.60	3.00	0.102	0.118	
L1	0.30	0.60	0.012	0.024	
Lp	0.40	0.70	0.016	0.028	
Q	0.20	0.30	0.008	0.012	
х		0.10	_	0.004	
У	_	0.10	_	0.004	

DIM	MILIMI	ETERS	INCHES		
DIM	MIN MAX		MIN	MAX	
e1	2.	2.10		08	
b2		0.60	-	0.024	
11	-	0.90	-	0.035	

Dimension in mm/inches

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